

RD74LVC14B

Hex Schmitt-trigger Inverters

REJ03D0218-0100Z Rev.1.00 Apr.09.2004

Description

The RD74LVC14B has six Schmitt trigger inverters in a 14-pin package. Low voltage and high-speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V}$
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V)
- Typical V_{OL} ground bounce < 0.8 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.0 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- High output current ± 4 mA (@V_{CC} = 1.65 V) ± 8 mA (@V_{CC} = 2.3 V) ± 12 mA (@V_{CC} = 2.7 V) ± 24 mA (@V_{CC} = 3.0 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
RD74LVC14BFPEL	SOP-14 pin (JEITA)	FP-14DAV	FP	EL (2,000 pcs/reel)
RD74LVC14BTELL	TSSOP-14 pin	TTP-14DV	Т	ELL (2,000 pcs/reel)

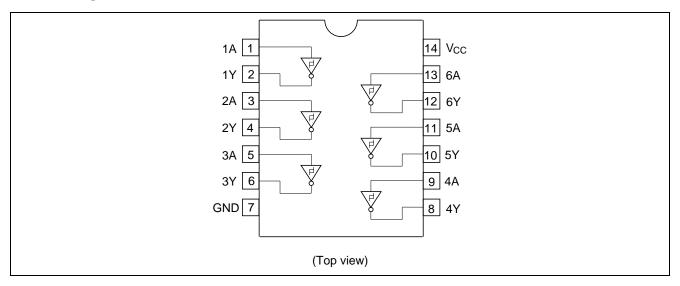
Function Table

Input A	Output Y
L	Н
Н	L

H: High level L: Low level

Pin Arrangement

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Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	Vcc	-0.5 to 7.0	V	
Input diode current	l _{IK}	- 50	mA	$V_1 = -0.5 \text{ V}$
Input voltage	Vı	-0.5 to 7.0	V	
Output diode current	Іок	- 50	mA	$V_0 = -0.5 \text{ V}$
		50		$V_O = V_{CC} + 0.5 V$
Output voltage	Vo	-0.5 to V _{CC} +0.5	V	
Output current	lo	±50	mA	
V _{CC} , GND current / pin	I _{CC} or I _{GND}	100	mA	
Storage temperature	Tstg	-65 to +150	°C	

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	Vcc	1.5 to 5.5	V	Data hold
		1.65 to 5.5		At operation
Input / Output voltage	VI	0 to 5.5	V	A
	Vo	0 to V _{CC}		Υ
Operating temperature	Та	-40 to 85	°C	
Output current	l _{OH}	-4	mA	$V_{CC} = 1.65 \text{ V}$
		- 8		$V_{CC} = 2.3 \text{ V}$
		- 12		$V_{CC} = 2.7 \text{ V}$
		-24		$V_{CC} = 3.0 \text{ V to } 5.5 \text{ V}$
	loL	4	mA	V _{CC} = 1.65 V
		8		$V_{CC} = 2.3 \text{ V}$
		12		$V_{CC} = 2.7 \text{ V}$
		24		$V_{CC} = 3.0 \text{ V to } 5.5 \text{ V}$



Electrical Characteristics

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			Ta = -40 to	85°C		
Item	Symbol	V _{cc} (V)	Min	Max	Unit	Test Conditions
Threshould voltage	V_T^+	1.65	0.4	1.3	V	
		1.95	0.6	1.5		
		2.3	0.8	1.7		
		2.5	0.8	1.7		
		2.7	1.0	2.0		
		3.0	1.2	2.2		
		3.6	1.5	2.4		
		4.5	1.6	2.6		
		5.5	2.0	3.0		
	V_T^-	1.65	0.15	0.85	V	
		1.95	0.25	0.95		
		2.3	0.4	1.2		
		2.5	0.4	1.2		
		2.7	0.4	1.4		
		3.0	0.6	1.5		
		3.6	0.8	1.8		
		4.5	1.0	2.0		
		5.5	1.4	2.4		
Hysteresis voltage	ΔV_{T}	1.65	0.10	1.15	V	$V_T^+ - V_T^-$
		1.95	0.15	1.25		
		2.3	0.25	1.3		
		2.5	0.25	1.3		
		2.7	0.3	1.1		
		3.0	0.4	1.2		
		3.6	0.4	1.2		
		4.5	0.4	1.2		
		5.5	0.4	1.2		
Input voltage	V_{OH}	1.65 to 5.5	V _{CC} -0.2	_	V	$I_{OH} = -100 \mu A$
		1.65	1.2	_		$I_{OH} = -4 \text{ mA}$
		2.3	1.7	_		$I_{OH} = -8 \text{ mA}$
		2.7	2.2	_		$I_{OH} = -12 \text{ mA}$
		3.0	2.4	_		
		3.0	2.2	_		$I_{OH} = -24 \text{ mA}$
		4.5	3.8	_		
	V_{OL}	1.65 to 5.5	<u> </u>	0.2	V	I _{OL} = 100 μA
		1.65	-	0.45		$I_{OL} = 4 \text{ mA}$
		2.3	<u> </u>	0.7		$I_{OL} = 8 \text{ mA}$
		2.7	<u> </u>	0.4		I_{OL} = 12 mA
		3.0	<u> </u>	0.55		$I_{OL} = 24 \text{ mA}$
		4.5	<u> </u>	0.55		
Input current	I _{IN}	0 to 5.5	_	±5.0	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Quiescent supply	I _{CC}	2.7 to 3.6	_	±5.0	μΑ	$V_{IN} = 3.6 \text{ V to } 5.5 \text{ V}$
current		2.7 to 5.5	_	5.0		$V_{IN} = V_{CC}$ or GND
	ΔI_{CC}	2.7 to 3.6	_	500	μΑ	V _{IN} = one input at
						(V _{CC} -0.6)V,
						other inputs at V _{CC} or GND

Switching Characteristics

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			Т	a = -40 to	o 85°C		From	То
Item	Symbol	V _{CC} (V)	Min	Тур	Max	Unit	(Input)	(Output)
Propagation delay time	t _{PLH}	1.8±0.15	1.0	_	11.0	ns	Α	Υ
	t_{PHL}	2.5±0.2	1.0	_	7.8			
		2.7	1.0	_	7.5	_		
		3.3±0.3	1.0	_	6.4	_		
		5.0±0.5	1.0	_	6.0	_		
Between output pins skew*1	t _{OSLH}	1.8±0.15	_	_	_	ns		
	toshl	2.5±0.2	_	_	_			
		2.7	_	_	_	_		
		3.3±0.3	_	_	1.0	_		
		5.0±0.5	_	_	1.0			
Input capacitance	C _{IN}	3.3	_	5.0	_	pF		

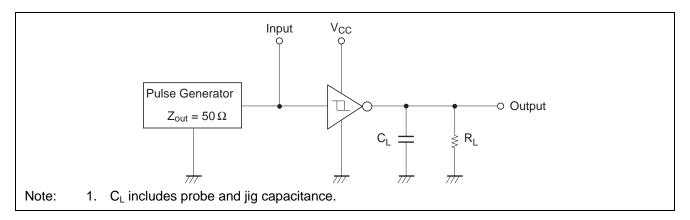
Note: 1. This parameter is characterized but not tested.

 $t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

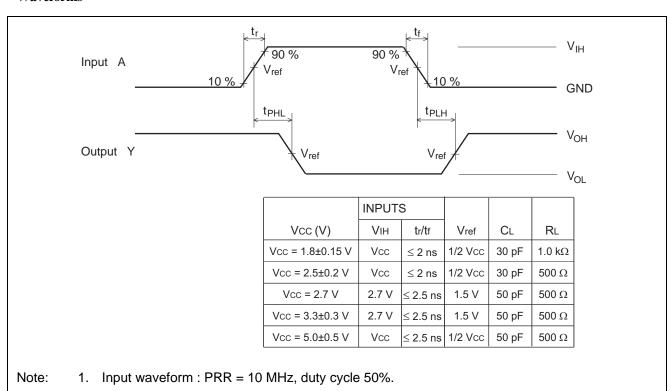
Operating Characteristics

		,	Ta = 2	Ta = 25°C			
Item	Symbol	V _{CC} (V)	Min	Тур	Max	Unit	Test conditions
Power dissipation	C_{PD}	1.8	_	16	_	pF	f = 10 MHz
Capacitance		2.5	_	18	_		
		3.3	_	20	_		
		5.0	_	25	_		

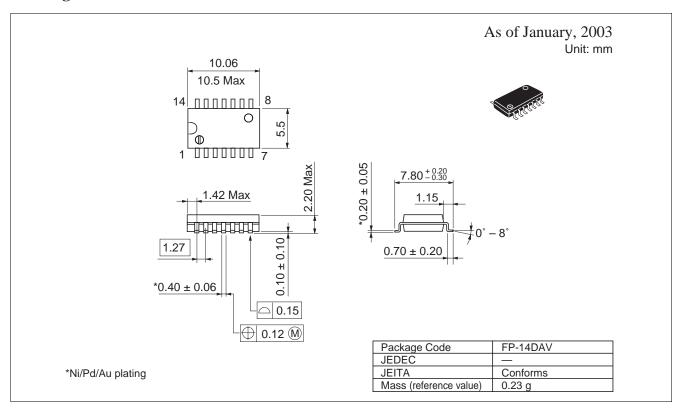
Test Circuit www.DataSheet4U.com

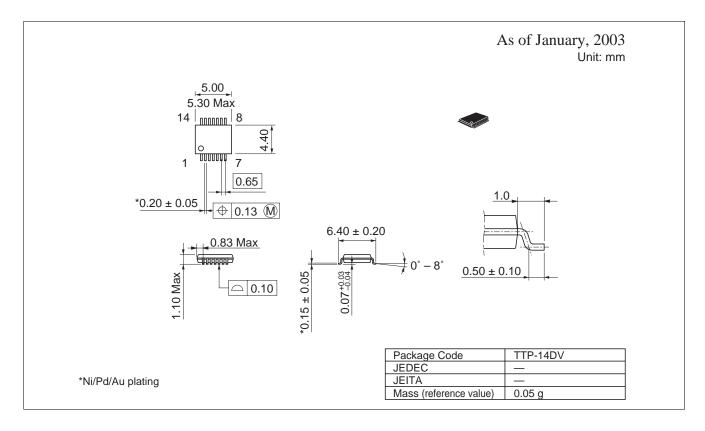


Waveforms



Package Dimensions





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